



PJD55N03

30V N-Channel MOSFET

Voltage

30 V

Current

55A

Features

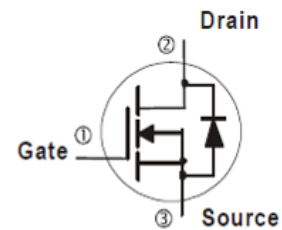
- $R_{DS(ON)}, V_{GS}@10V, I_D@16A < 9m\Omega$
- $R_{DS(ON)}, V_{GS}@4.5V, I_D@8A < 13m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.
(Halogen Free)

Mechanical Data

- Case: TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams



TO-252AA



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	+20	V
Continuous Drain Current	$T_C=25^\circ\text{C}$	I_D	55	A
	$T_C=100^\circ\text{C}$		35	
Pulsed Drain Current ^(Note 1)		I_{DM}	220	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	40	W
	$T_C=100^\circ\text{C}$		16	
Continuous Drain Current	$T_A=25^\circ\text{C}$	I_D	12.2	A
	$T_A=70^\circ\text{C}$		9.7	A
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	2	W
Power Dissipation	$T_A=70^\circ\text{C}$		1.3	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal resistance ^(Note 4,5)	Junction to Case	$R_{\theta JC}$	3.1	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



PJD55N03

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.6	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=16A$	-	7.7	9	m Ω
		$V_{GS}=4.5V, I_D=8A$	-	10	13	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Dynamic (Note 4)						
Total Gate Charge	Q_g	$V_{DS}=15V, I_D=20A,$ $V_{GS}=4.5V$ (Note 2,3)	-	7.2	-	nC
Gate-Source Charge	Q_{gs}		-	1	-	
Gate-Drain Charge	Q_{gd}		-	4.2	-	
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	740	-	pF
Output Capacitance	C_{oss}		-	130	-	
Reverse Transfer Capacitance	C_{rss}		-	100	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=15V, I_D=15A,$ $V_{GS}=10V, R_G=3.3\Omega$ (Note 2,3)	-	4.2	-	ns
Turn-On Rise Time	t_r		-	12.2	-	
Turn-Off Delay Time	$t_{d(off)}$		-	27.4	-	
Turn-Off Fall Time	t_f		-	7.8	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	55	A
Diode Forward Voltage	V_{SD}	$I_S=1A, V_{GS}=0V$	-	-	1	V

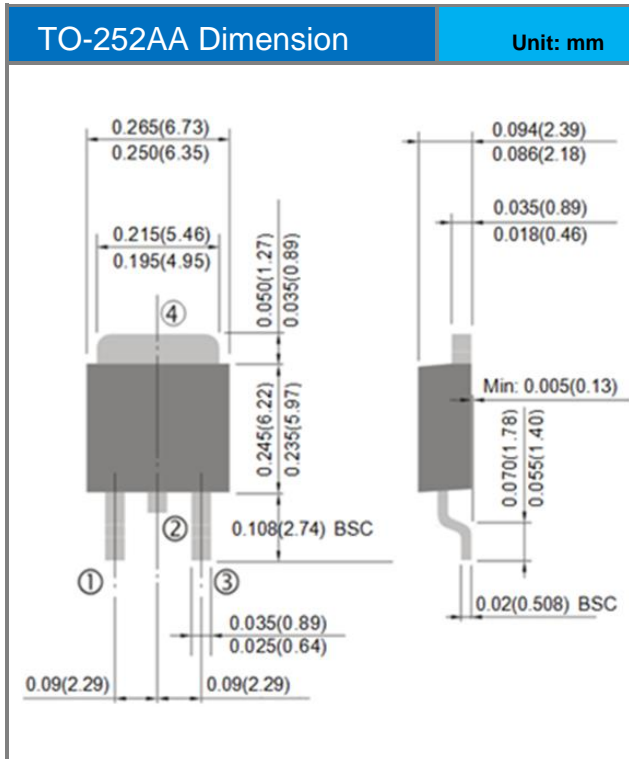
NOTES:

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics
3. Repetitive rating, pulse width limited by junction temperature $T_J(\text{MAX})=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ\text{C}$.
4. The maximum current rating is package limited
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing



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Packaging Information



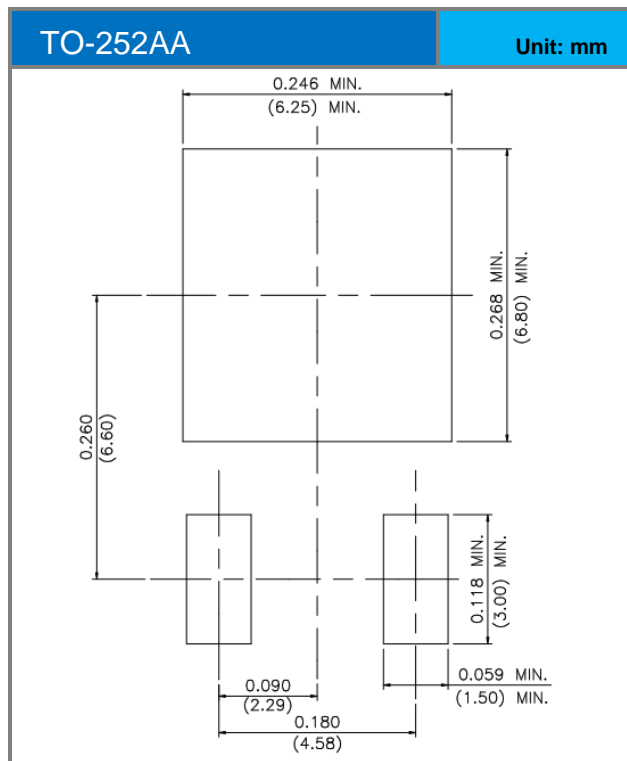


PJD55N03

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD55N03_L2_00001	TO-252AA	3,000pcs / 13" reel	D55N03	Halogen free

MOUNTING PAD LAYOUT





PJD55N03

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